SCES074E - JUNE 1996 - REVISED JANUARY 1999

- State-of-the-Art Advanced BiCMOS Technology (ABT) *Widebus*[™] Design for 2.5-V and 3.3-V Operation and Low Static Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$
- Power Off Disables Outputs, Permitting Live Insertion
- High-Impedance State During Power Up and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Output Ports Have Equivalent 30-Ω Series Resistors, So No External Resistors Are Required
- Auto3-State Eliminates Bus Current Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates Printed Circuit Board Layout
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

NOTE: For order entry: The DGG package is abbreviated to G, and the DGV package is abbreviated to V.

description

The 'ALVTH162244 devices are 16-bit buffers/line drivers designed for low-voltage 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments Incorporated

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SN54ALVTH162244 WD PACKAGE
SN74ALVTH162244 DGG, DGV, OR DL PACKAGE
(TOP VIEW)

1Y1 2 47 1A1 1Y2 3 46 1A2 GND 4 45 GND 1Y3 5 44 1A3 1Y4 6 43 1A4 V _{CC} 7 42 V _{CC} 2Y1 8 41 2A1 2Y2 9 40 2A2 GND 10 39 GND 2Y3 11 38 2A3 2Y4 12 37 2A4 3Y1 13 36 3A1 3Y2 14 35 3A2 GND 15 34 GND 3Y3 16 33 3A3 3Y4 17 32 3A4 V _{CC} 18 31 V _{CC} 4Y1 19 30 4A1	(TOP VIEW)									
3Y2 14 35 3A2 GND 15 34 GND 3Y3 16 33 3A3 3Y4 17 32 3A4 V _{CC} 18 31 V _{CC} 4Y1 19 30 4A1 4Y2 20 29 4A2 GND 21 28 GND 4Y3 22 27 4A3 4Y4 23 26 4A4	10E 1Y1 1Y2 GND 1Y3 1Y4 Vcc 2Y1 2Y2 GND 2Y3 2Y3 2Y4	1 2 3 4 5 6 7 8 9 10 11 12	48 47 46 45 44 43 42 41 40 39 38 37] 1A2] GND] 1A3] 1A4] V _{CC}] 2A1] 2A2] GND] 2A3] 2A4						
V _{CC} 18 31 V _{CC} 4Y1 19 30 4A1 4Y2 20 29 4A2 GND 21 28 GNE 4Y3 22 27 4A3 4Y4 23 26 4A4	GND	-	-] GND						
	3Y4 V _{CC} 4Y1 4Y2 GND 4Y3	18 19 20 21 22	31 30 29 28 27] 3A4 V _{CC} 4A1 4A2 GND 4A3						
		24	25	L						

SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E – JUNE 1996 - REVISED JANUARY 1999

description (continued)

These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. These devices provide true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

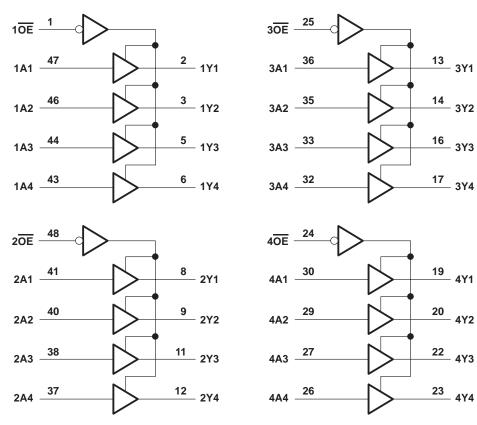
When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

All outputs are designed to sink up to 12 mA and include equivalent $30-\Omega$ resistors to reduce overshoot and undershoot.

The SN54ALVTH162244 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALVTH162244 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)									
INPUTS OUTPUT									
OE	Α	Y							
L	Н	Н							
L	L	L							
Н	Х	Z							

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_CC $\ldots \ldots $
Input voltage range, V _I (see Note 1) –0.5 V to 7 V
Voltage range applied to any output in the high-impedance
or power-off state, V _O (see Note 1)
Voltage range applied to any output in the high state, V _O (see Note 1) –0.5 V to 7 V
Output current in the low state, I _O
Output current in the high state, I _O
Input clamp current, I_{IK} (V _I < 0) -50 mA
Output clamp current, I_{OK} (V _O < 0)
Package thermal impedance, θ_{JA} (see Note 2): DGG package
DGV package
DL package
Storage temperature range, T _{stg}

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

		SN54A	LVTH16	62244	SN74ALVTH162244			UNIT	
		MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
Vcc	Supply voltage	2.3		2.7	2.3		2.7	V	
VIH	High-level input voltage	1.7		h	1.7			V	
VIL	Low-level input voltage		Vin.	0.7			0.7	V	
VI	Input voltage	0	Vcc	5.5	0	VCC	5.5	V	
ЮН	High-level output current			1	-6			-8	mA
IOL	Low-level output current			22	8			12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	20,	5	10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
ТА	Operating free-air temperature	-55		125	-40		85	°C	

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions, V_{CC} = 3.3 V \pm 0.3 V (see Note 3)

		SN54A	LVTH16	2244	SN74ALVTH162244			UNIT	
		MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
VCC	Supply voltage	3		3.6	3		3.6	V	
VIH	High-level input voltage	2		W.	2			V	
VIL	Low-level input voltage		ľu,	0.8			0.8	V	
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
ЮН	High-level output current			1	-8			-12	mA
IOL	Low-level output current			22	8			12	mA
Δt/Δv	Input transition rise or fall rate	ut transition rise or fall rate Outputs enabled		5	10			10	ns/V
Δt/ΔVCC	Power-up ramp rate	200			200			μs/V	
ТА	Operating free-air temperature	-55		125	-40		85	°C	

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

D.	ARAMETER	TEST CO	SN54A	LVTH1	62244	SN74ALVTH162244			UNIT		
Ρ/	ARAMETER	TEST CO	NDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII	
VIK		V _{CC} = 2.3 V,	lj = -18 mA			-1.2			-1.2	V	
		V _{CC} = 2.3 V to 2.7 V,	I _{OH} = -100 μA	V _{CC} -0.2	2		V _{CC} -0.	.2			
VOH			I _{OH} = -6 mA	1.7						V	
		$V_{CC} = 2.3 V$	IOH = -8 mA				1.7				
		V_{CC} = 2.3 V to 2.7 V,	I _{OL} = 100 μA			0.2			0.2		
VOL		V _{CC} = 2.3 V	I _{OL} = 8 mA			0.7				V	
		VCC = 2.3 V	I _{OL} = 12 mA						0.7		
	Control	V _{CC} = 2.7 V,	$V_I = V_{CC} \text{ or } GND$			±1			±1		
inputs	inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	VI = 5.5 V			10			10		
lj –			V _I = 5.5 V			10			10	μA	
	Data inputs	a inputs $V_{CC} = 2.7 V$	$V_I = V_{CC}$			\$ 1			1		
			$V_{I} = 0$			-5			-5		
loff		$V_{CC} = 0,$	V_{I} or V_{O} = 0 to 4.5 V		7				±100	μA	
I _{BHL} ‡	ŧ	V _{CC} = 2.3 V,	V _I = 0.7 V		115			115		μA	
IBHH		V _{CC} = 2.3 V,	V _I = 1.7 V		5-10			-10		μΑ	
BHLO	o¶	V _{CC} = 2.7 V,	$V_I = 0$ to V_{CC}	300	5		300			μA	
IBHH	0 [#]	V _{CC} = 2.7 V,	$V_I = 0$ to V_{CC}	-300			-300			μA	
IEX		V _{CC} = 2.3 V,	V _O = 5.5 V			125			125	μA	
IOZ(F	PU/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_O = 0.5 \text{ V} \text{ to}$ $V_I = \text{GND or } V_{CC}, \overline{\text{OE}} = \text{dot}$	o V _{CC} , on't care			±100			±100	μΑ	
IOZH		V _{CC} = 2.7 V	V _O = 2.3 V, V _I = 0.7 V or 1.7 V			5			5	μA	
I _{OZL}		V _{CC} = 2.7 V	V _O = 0.5 V, V _I = 0.7 V or 1.7 V			-5			-5	μA	
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1		
ICC		$I_{O} = 0,$	Outputs low		2.3	4.5		2.3	4.5	mA	
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3			3		pF	
Co		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		6			6		pF	

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

S The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 \P An external driver must source at least I_{BHLO} to switch this node from low to high.

An external driver must sink at least IBHHO to switch this node from high to low.

I Current into an output in the high state when $V_{O} > V_{CC}$

*High-impedance state during power up or power down



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

DA	RAMETER	TEST O		SN54A	LVTH1	62244	SN74/	ALVTH16	62244	UNIT		
FA	RANIEIER		ONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT		
VIK		V _{CC} = 3 V,	lı = –18 mA			-1.2			-1.2	V		
		V _{CC} = 3 V to 3.6 V,	I _{OH} = −100 μA	V _{CC} -0.	2		V _{CC} -0	.2				
∨он			I _{OH} = -8 mA	2								
		VCC = 3 V	$I_{OH} = -12 \text{ mA}$				2					
		V _{CC} = 3 V to 3.6 V,	I _{OL} = 100 μA			0.2			0.2			
Vol			IOL = 8 mA			0.8				V		
		VCC = 3 V	I _{OL} = 12 mA						0.8			
	Control	V _{CC} = 3.6 V,	$V_I = V_{CC} \text{ or } GND$			±1			±1			
	inputs	V _{CC} = 0 or 3.6 V	Vj = 5.5 V			10			10			
Ι			V _I = 5.5 V			10			10	μA		
	Data inputs	ts $V_{CC} = 3.6 V$	$V_{I} = V_{CC}$			1			1			
			VI = 0	_5					-5			
l _{off}		V _{CC} = 0,	V_{I} or V_{O} = 0 to 4.5 V		72	, 			±100	μA		
I _{BHL} ‡	:	V _{CC} = 3 V,	V _I = 0.8 V	75	5		75			μA		
I _{BHH} §	Ì	V _{CC} = 3 V,	V _I = 2 V	-75	2		-75			μA		
BHLC	P	V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	500	<u>S</u>		500			μA		
Івнно	D [#]	V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	-500			-500			μA		
IEX		V _{CC} = 3 V,	V _O = 5.5 V			125			125	μA		
IOZ(P	U/PD)☆	$V_{CC} \le 1.2 \text{ V}, \text{ V}_{O} = 0.5 \text{ V}$ V _I = GND or V _{CC} , OE = 0	to V _{CC} , don't care			±100			±100	μΑ		
I _{OZH}		V _{CC} = 3.6 V	V _O = 3 V, V _I = 0.8 V or 2 V			5			5	μΑ		
I _{OZL}		V _{CC} = 3.6 V	V _O = 0.5 V, V _I = 0.8 V or 2 V			-5			-5	μA		
		V _{CC} = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1			
ICC		$I_{O} = 0,$	Outputs low		3.2	5		3.2	5	mA		
		$V_I = V_{CC}$ or GND	Outputs disabled		0.07	0.1		0.07	0.1			
		$V_{CC} = 3 V$ to 3.6 V, One Other inputs at V_{CC} or G				0.4			0.4	mA		
Ci		V _{CC} = 3.3 V,	VI = 3.3 V or 0		3			3		pF		
Co		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF		

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25° C.

[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

§ The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

 \P An external driver must source at least I_{BHLO} to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

I Current into an output in the high state when $V_O > V_{CC}$

*High-impedance state during power up or power down

□ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E - JUNE 1996 - REVISED JANUARY 1999

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALVTH	1162244	SN74ALVTH	UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	v	1	4.3	1	4.2	ns
^t PHL	~		1.4	3.8	1.5	3.7	115
^t PZH	OE	v	1.3	6.9	1.4	6.8	ns
^t PZL	UE		1.3	5.2	1.4	5.1	115
^t PHZ	OE	v	50	4.7	1	4.6	ns
^t PLZ	UE		Q 1	3.6	1	3.5	115

switching characteristics over recommended operating free-air temperature range, CL = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH1	62244	SN74ALVTH	UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
^t PLH	٨	V	1	3.4	1	3.3	200
^t PHL	А	T	1	3.4	1	3.3	ns
^t PZH	ŌĒ	V	1.4	5	1.5	4.9	ns
^t PZL	OE	T	1.3	3.4	1.4	3.3	115
^t PHZ	ŌĒ	V	1.4	5	1.5	4.9	ns
^t PLZ	UE	I	2 1.4	4.4	1.5	4.3	115



SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCES074E – JUNE 1996 - REVISED JANUARY 1999

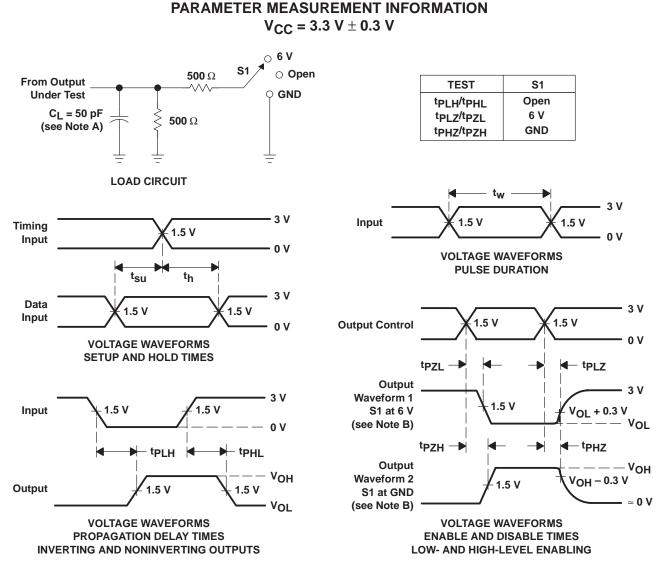
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 V \pm 0.2 V$ $\odot 2 \times V_{CC}$ **S1** O Open **500** Ω **From Output** TEST **S1** $\wedge \wedge \wedge$ O GND **Under Test** Open tPLH/tPHL $C_L = 30 \text{ pF}$ $2 \times V_{CC}$ ^tPLZ^{/t}PZL **500** Ω (see Note A) GND tPHZ/tPZH LOAD CIRCUIT tw Vcc Vcc Input V_{CC}/2 V_{CC}/2 Timing V_{CC}/2 0 V Input 0 V **VOLTAGE WAVEFORMS** PULSE DURATION t_{su} t_h Vcc Output Data Vcc V_{CC}/2 V_{CC}/2 Control Input V_{CC}/2 V_{CC}/2 (low-level 0 V 0 V enabling) **VOLTAGE WAVEFORMS** SETUP AND HOLD TIMES - tplz tp7I Output Vcc Vcc Waveform 1 V_{CC}/2 V_{CC}/2 S1 at $2 \times V_{CC}$ Input V_{CC}/2 V_{OL} + 0.15 V (see Note B) 0 V Vol ^tPZH ^tPHZ ^tPHL **t**PLH Output – Vон VOH Waveform 2 V_{OH} – 0.15 V V_{CC}/2 Output V_{CC}/2 V_{CC}/2 S1 at GND 0 V VOL (see Note B) **VOLTAGE WAVEFORMS VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES ENABLE AND DISABLE TIMES**

- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms





PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74ALVTH162244DL	OBSOLETE	SSOP	DL	48		TBD	Call TI	Call TI	-40 to 85	ALVTH162244	
SN74ALVTH162244GR	OBSOLETE	TSSOP	DGG	48		TBD	Call TI	Call TI	-40 to 85	ALVTH162244	
SN74ALVTH162244LR	OBSOLETE	SSOP	DL	48		TBD	Call TI	Call TI	-40 to 85	ALVTH162244	
SN74ALVTH162244VR	OBSOLETE	TVSOP	DGV	48		TBD	Call TI	Call TI	-40 to 85	VT2244	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



DGG0048A

DGG0048A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DGG0048A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate

design recommendations. 8. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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